NSN 5962-01-285-3500

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View Online at https://aerobasegroup.com/nsn/5962-01-285-3500
Body Length:
Between 0.540 inches and 0.560 inches
Body Width:
Between 0.442 inches and 0.458 inches
Body Height:
Between 0.060 inches and 0.120 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and programmable and burn in and ultraviolet erasable and w/enable
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
C-12 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Prom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
32 leadless

N/a

Shelf Life:

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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